









	<p>RFD16N05</p>
	<p>Hersteller-Teilenummer: RFD16N05</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 50V 16A I-PAK</p> <p>Datenblätter:  RFD16N05.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8757 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RFD16N05
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 50V 16A I-PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	8757 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	TO-251AA
Verlustleistung (max)	72W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	47 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 20V
Eingabekapazität (Ciss) (Max) @ Vds	900pF @ 25V
Verpackung	Tube



















































RFD16N05 ist neu im Original, Suche RFD16N05 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD16N05 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage RFD16N05: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD16N05LM FAIRCHI RFD16N05LM FAIRCHI</p>	 <p>RFD16N05 AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A I-PAK</p>	 <p>RFD16N05LSM Fairchild/ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p>RFD16N03LSM FAI RFD16N03LSM FAI</p>
 <p>RFD16N05LSM AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>	 <p>RFD16N03L INFINEON RFD16N03L INFINEON</p>	 <p>RFD16N03 F F TO-252</p>	 <p>RFD16N02LSM9A INTERSIL RFD16N02LSM9A INTERSIL</p>

heiße Teile

Mehr

 RFD14N05SM	 RFD14N05SM9	 RFD14N05SM9A	 RFD14N05SM9A	 RFD15N05
 RFD15N05LSM	 RFD15N06LE	 RFD15N06LESM	 RFD15P05	 RFD15P05
 RFD15P05SM	 RFD15P05SM	 RFD15P05SM9A	 RFD15P06	 RFD15P06LSM
 RFD15P06SM	 RFD15P06SM9AS2463	 RFD16N02	 RFD16N02L	 RFD16N02LSM
 RFD16N02LSM9A	 RFD16N03L	 RFD16N03LSM	 RFD16N03LSM9A	 RFD16N05
 RFD16N05L	 RFD16N05LSM	 RFD16N05LSM	 RFD16N05LSM-NL	 RFD16N05LSM96S5000
 RFD16N05LSM9A	 RFD16N05LSM9A	 RFD16N05SM	 RFD16N05SM	 RFD16N05SM9A
 RFD16N05SM9A	 RFD16N06	 RFD16N06L	 RFD16N06LESM	 RFD16N06LESM9A
 RFD16N06LESM9A	 RFD16N06SM9A	 RFD20N03SM	 RFD20N03SM9A	 RFD3055L
 RFD3055LE	 RFD3055LE	 RFD3055LESM	 RFD3055LESM	 RFD3055LESM9A

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